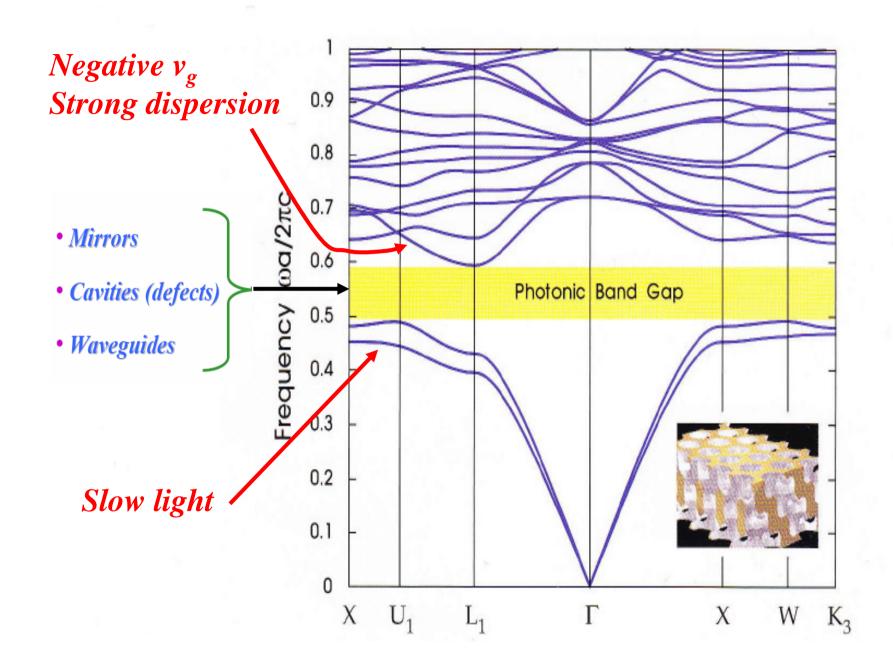
Applicazioni Fotonica 2: Emissione



Densità di stati fotonici nel vuoto

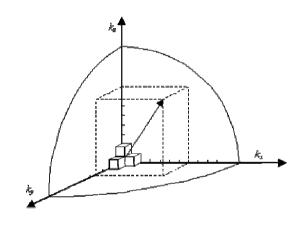
Volume in k-space per state $(2\pi/L)^3$

Volume in k-space occupied by states with frequency less than ω

$$V_k = 4\pi k^3/3$$
 where $k = \omega/c$

Number of photon states in this volume

$$N(\omega) = 2\frac{4\pi k^3 / 3}{(2\pi / L)^3} = \frac{L^3}{3\pi^2} \frac{(\omega)^3}{c^3}$$



Density of states with frequency $(\omega, \omega+d\omega)$ per unit volume

$$\rho(\omega) = \frac{1}{L^3} \frac{dN(\omega)}{d\omega} = \frac{\omega^2}{\pi^2 c^3}$$

Emissione spontanea

$$\Gamma = \frac{2\pi}{\hbar} \sum_{\vec{k},\lambda} \left| \left\langle \vec{d} \cdot \vec{E}_{\vec{k},\lambda}(\vec{r}) \right\rangle \right|^2 \delta(\hbar \omega_0 - \hbar \omega_k)$$
 Regola aurea Fermi

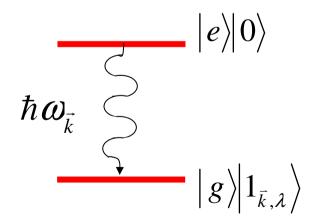
Campo quantizzato

$$\vec{E}_{\vec{k},\lambda}(\vec{r}) = i \left(\frac{\hbar \omega_k}{2\varepsilon_0 V}\right)^{1/2} \left[\hat{a}_{\vec{k},\lambda} e^{i\vec{k}\cdot\vec{r}} - \hat{a}_{\vec{k},\lambda}^+ e^{-i\vec{k}\cdot\vec{r}}\right] \vec{e}_{\vec{k},\lambda}$$

Stati coinvolti

$$|0,e\rangle \Rightarrow |1_{\vec{k},\lambda},g\rangle$$

$$\hbar \omega_{\vec{k}} = E_e - E_g = \hbar \omega_0$$



Emissione spontanea

Sostituendo

$$\Gamma_{0} = \sum_{\vec{k},\lambda} \frac{2\pi}{\hbar} \left| \left\langle \vec{d} \cdot \vec{e}_{\vec{k},\lambda} \right\rangle \right|^{2} \left(\frac{\hbar \omega_{k}}{2\varepsilon_{0} V} \right) \delta(\hbar \omega - \hbar \omega_{k}) =$$

$$= \frac{\pi |d|^{2} \omega}{3\varepsilon_{0}} \sum_{\vec{k}} \frac{2}{V} \sum_{\vec{k}} \delta(\hbar \omega - \hbar \omega_{k}) = \frac{\pi |d|^{2} \omega}{3\varepsilon_{0}} \rho(\hbar \omega) =$$

$$= \frac{\pi |d|^{2} \omega}{3\varepsilon_{0}} \frac{\omega^{2}}{\pi^{2} c^{3}} \frac{1}{\hbar} = \frac{4}{3} \frac{1}{4\pi\varepsilon_{0}} \frac{|d|^{2} \omega^{3}}{\hbar \pi^{2} c^{3}}$$

Densità di stati fotonici PhC

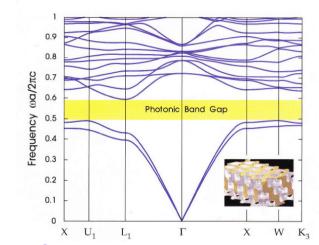
Volume in k-space per state $(2\pi/L)^3$

Volume in k-space occupied by states with frequency less than ω

$$V_k = V(\omega(\vec{k}))$$
 where $\omega = \omega(\vec{k})$

Number of photon states in this volume

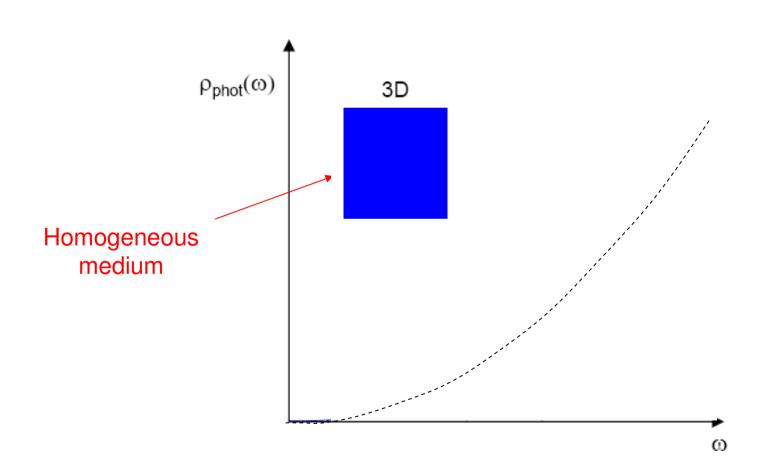
$$N(\omega(\vec{k})) = 2\frac{V(\omega(\vec{k}))}{(2\pi/L)^3}$$



Density of states with frequency (\omega, \omega+d\omega) per unit volume

$$\rho(\omega) = \frac{1}{L^3} \frac{dN(\omega(\vec{k}))}{d\omega} = \frac{1}{L^3} \vec{\nabla}_{\vec{k}} N(\omega(\vec{k})) \cdot \frac{d\vec{k}}{d\omega} \implies \approx \frac{1}{v_g}$$

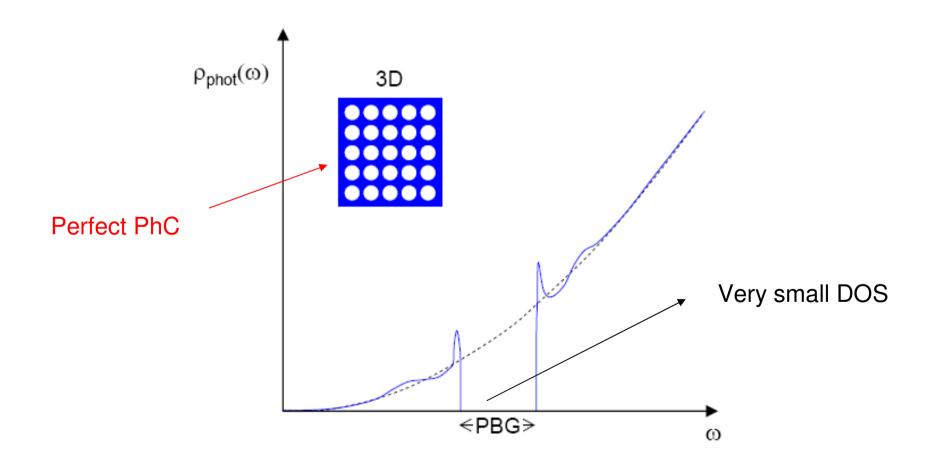
Densità di stati fotonici in mezzi isotropi



Densità di stati fotonici PhC

Photonic Band Gap:

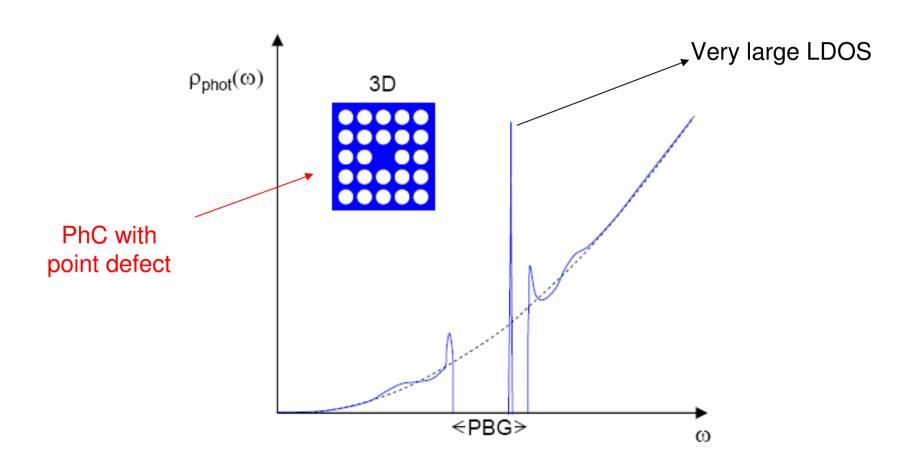
Ultimate control over the photonic density of states



Densità di stati fotonici PhC con difetto

Photonic Band Gap:

Ultimate control over the photonic density of states



Purcell Effect - Control Spontaneous Emission

B10. Spontaneous Emission Probabilities at Radio Frequencies. E. M. Purcell, Harvard University.—For nuclear magnetic moment transitions at radio frequencies the probability of spontaneous emission, computed from

$$A_{\nu} = (8\pi\nu^2/c^3)h\nu(8\pi^3\mu^2/3h^2) \text{ sec.}^{-1}$$
,

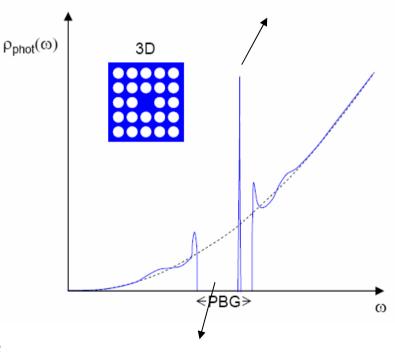
is so small that this process is not effective in bringing a spin system into thermal equilibrium with its surroundings. At 300°K, for $\nu = 10^7$ sec. 1, $\mu = 1$ nuclear magneton, the corresponding relaxation time would be 5×1021 seconds! However, for a system coupled to a resonant electrical circuit, the factor 8 m v2/c3 no longer gives correctly the number of radiation oscillators per unit volume, in unit frequency range, there being now one oscillator in the frequency range ν/Q associated with the circuit. The spontaneous emission probability is thereby increased, and the relaxation time reduced, by a factor $f = 3Q\lambda^3/4\pi^2V$, where V is the volume of the resonator. If a is a dimension characteristic of the circuit so that $V \sim a^3$, and if δ is the skin-depth at frequency ν , $f \sim \lambda^3/a^2 \delta$. For a non-resonant circuit $f \sim \lambda^3/a^3$, and for $a < \delta$ it can be shown that $f \sim \lambda^3/a\delta^2$. If small metallic particles, of diameter 10-3 cm are mixed with a nuclear-magnetic medium at room temperature, spontaneous emission should establish thermal equilibrium in a time of the order of minutes, for $v = 10^7$ sec.⁻¹.

Purcell, Phys. Rev. 69, 681 (1946).

Proceedings of APS meeting April 1946

$$A(v) = A_0 \frac{8\pi v^2}{c^3} = A_0 \rho_{ph}(v)$$

Acceleration of the emission



Suppression of the emission

Emissione spontanea in microcavità

$$\Gamma = \frac{2\pi}{\hbar} \sum_{\mu} \left| \left\langle \vec{d} \cdot \vec{E}_{\mu}(\vec{r}) \right\rangle \right|^{2} \delta(\hbar \omega - \hbar \omega_{\mu})$$
 Regola aurea Fermi

Campo quantizzato in microcavità

$$\vec{E}_{\mu}(\vec{r}) = i \left(\frac{\hbar \omega_{\mu}}{2\varepsilon_{0}}\right)^{1/2} \left[\hat{a}_{\mu} \alpha_{\mu}(\vec{r}) - \hat{a}_{\mu}^{\dagger} \alpha_{\mu}^{\dagger}(\vec{r})\right] \vec{e}_{\mu}$$

Sostituendo
$$\Gamma = \sum_{\mu} \frac{2\pi}{\hbar} \left| \left\langle \vec{d} \cdot \vec{e}_{\mu} \alpha_{\mu}(\vec{r}) \right\rangle \right|^{2} \left(\frac{\hbar \omega_{\mu}}{2\varepsilon_{0}} \right) \delta(\hbar \omega - \hbar \omega_{\mu}) = \begin{cases} \pi |d|^{2} \omega \\ \varepsilon_{0} \end{cases} \sum_{\mu} \left| \alpha_{\mu}(\vec{r}) \right|^{2} \delta(\hbar \omega - \hbar \omega_{\mu}) = \begin{cases} \alpha_{\vec{k}}(\vec{r}) = \frac{e^{i\vec{k} \cdot \vec{r}}}{\sqrt{V}} \end{cases}$$

$$\Gamma_{\mu} = \frac{\pi |d|^2 \omega}{\varepsilon_0} |\alpha_{\mu}(\vec{r})|^2 \rho_{\mu}(\hbar \omega) \quad LDOS$$

$$\left| \int_{V} \left| \alpha_{\vec{k}}(\vec{r}) \right|^{2} dV = 1 \right|$$

$$\alpha_{\vec{k}}(\vec{r}) = \frac{e^{ik \cdot \vec{r}}}{\sqrt{V}}$$

Emissione spontanea in cavità

$$\Gamma_{\mu} = \frac{\pi |d|^2 \omega}{\varepsilon_0} |\alpha_{\mu}(\vec{r})|^2 \rho_{\mu}(\hbar \omega) =$$

$$= \frac{\pi |d|^2 \omega}{\varepsilon_0} |\alpha_{\mu}(\vec{r})|^2 \frac{1}{\hbar} \frac{1}{2\pi} \frac{\gamma_{\mu}}{(\omega - \omega_{\mu})^2 + \gamma_{\mu}^2 / 4}$$

Alla risonanza

$$\Gamma_{\mu} = \frac{\left|d\right|^{2} \omega}{\varepsilon_{0}} \left|\alpha_{\mu}(\vec{r})\right|^{2} \frac{1}{\hbar} \frac{2}{\gamma_{\mu}} =$$

$$= \frac{2\left|d\right|^{2} Q}{\hbar \varepsilon_{0}} \left|\alpha_{\mu}(\vec{r})\right|^{2} = \frac{2\left|d\right|^{2} Q}{\hbar \varepsilon_{0} V_{c}}$$

Il rate dipende dalla posizione dell'emettitore rispetto alla LDOS

$$\alpha_{\mu}(\vec{r}) \approx \frac{1}{\sqrt{V_C}}$$

Effetto Purcell

In cavità

$$\Gamma_{\mu} = \frac{2|d|^2 Q}{\hbar \varepsilon_0 V_c}$$

Nel vuoto

$$\Gamma_0 = \frac{4}{3} \frac{1}{4\pi\varepsilon_0} \frac{\left|d\right|^2 \omega^3}{\hbar c^3} = \frac{8\pi^2}{3\varepsilon_0 \hbar} \frac{\left|d\right|^2}{\lambda^3}$$

Fattore di Purcell

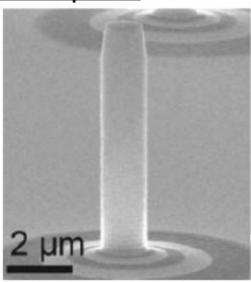
Confronto

$$\Gamma_{\mu} = \frac{2|d|^2 Q}{\hbar \varepsilon_0 V_c} = \frac{3}{4\pi^2} \frac{\lambda^3}{V_c} Q \Gamma_0 = F_P \Gamma_0$$

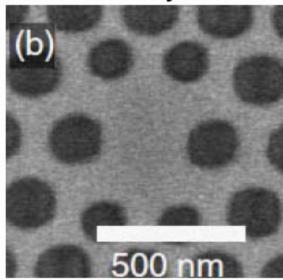
$$F_P = \frac{3}{4\pi^2} \frac{\lambda^3}{V_c} Q$$

Buone approssimazioni di cavità 3D

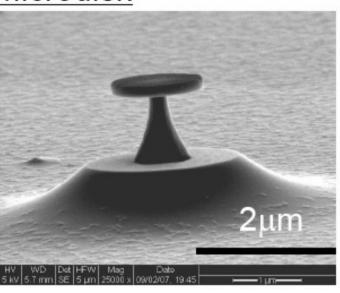
Micropillar



Photonic Crystal



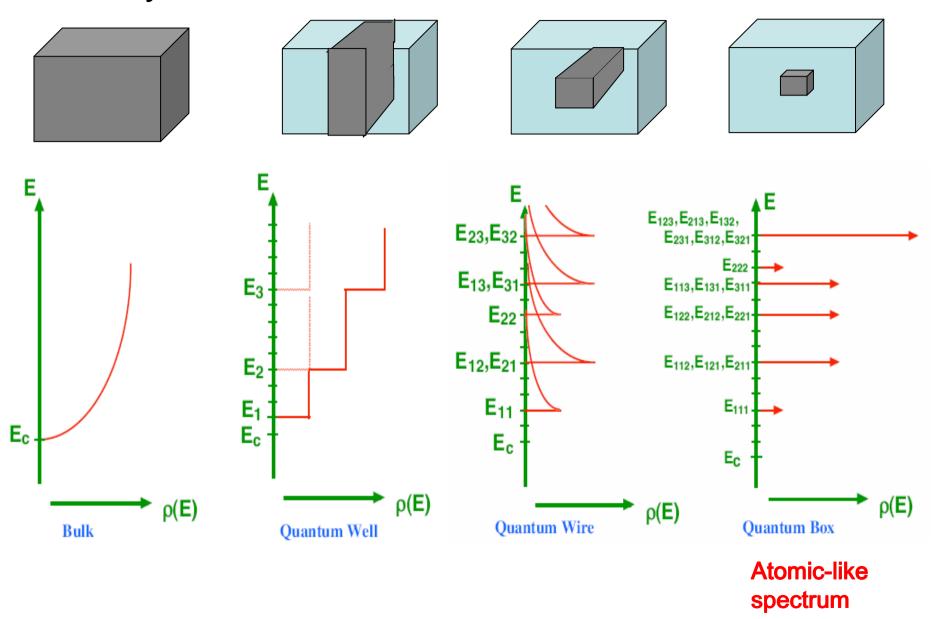
Microdisk



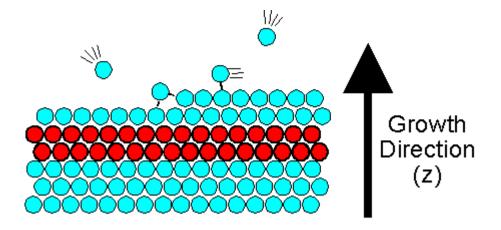
| | Micropillar | Photonic Crystal | Microdisk |
|----------|-------------|--------------------------|-----------|
| Q @930nm | 23000 | 30000 | 20000 |
| V | 5 (λ/n)³∼ | 0.5 (λ/n) ³ ~ | 5 (λ/n)³~ |
| Fp | 61 | 145 | 125 |

Emittitore a semiconduttore Quantum Dots

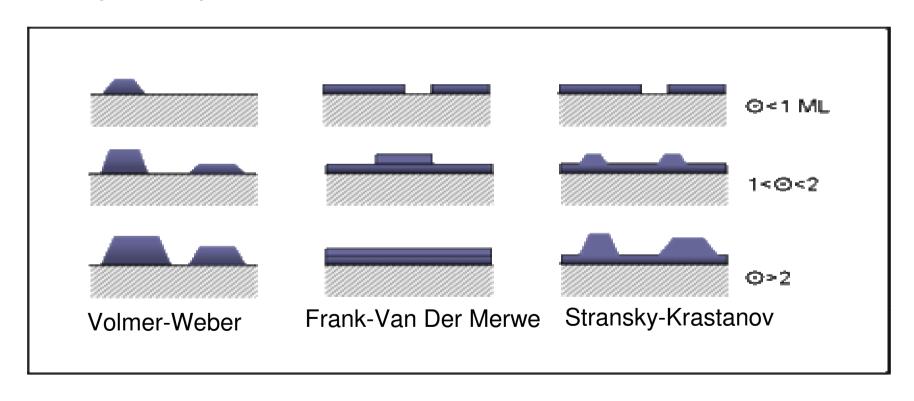
Density of states



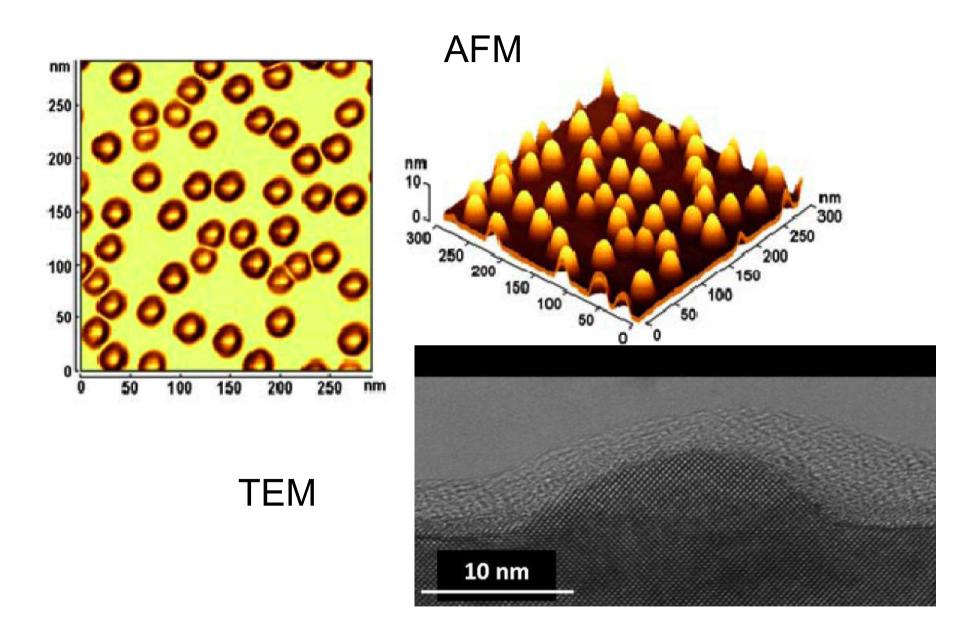
Crescita epitassiale



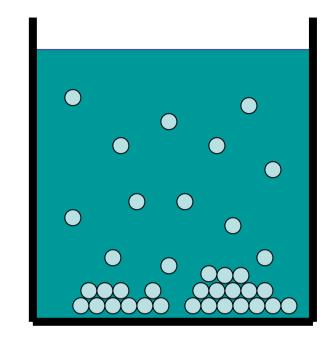
3 tipi di epitassia

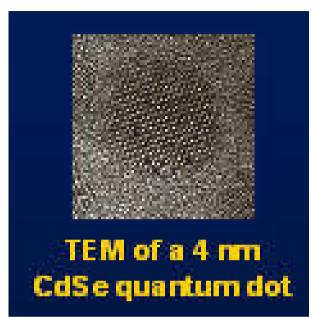


Quantum dots SK



Quantum dots Colloidali

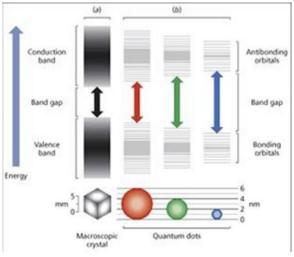


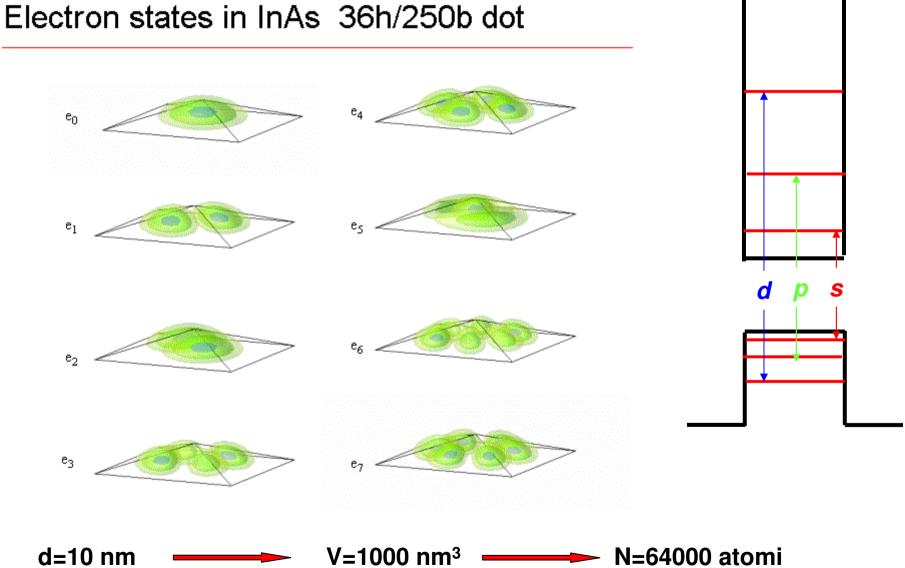




CdSe

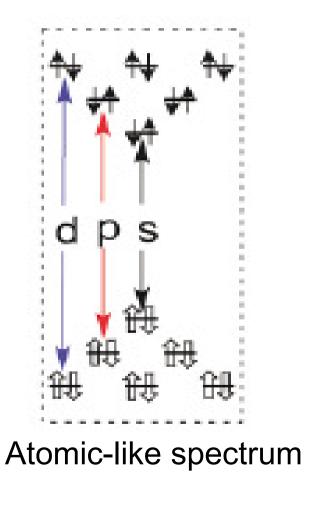






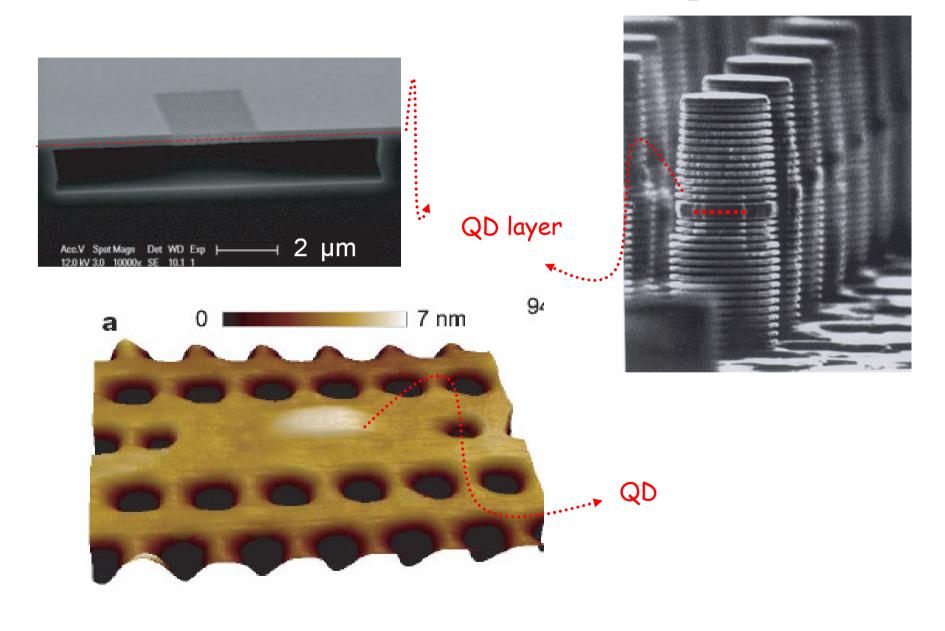
Excitonic Energy Shell Structure of Self-Assembled InGaAs/GaAs Quantum Dots

S. Raymond,¹ S. Studenikin,¹ A. Sachrajda,¹ Z. Wasilewski,¹ S. J. Cheng,¹ W. Sheng,¹ P. Hawrylak,¹ A. Babinski,^{2,4} M. Potemski,^{1,2} G. Ortner,³ and M. Bayer³



Misura di PL su molti QDs b) Intensity (a.u. 900 oC 875 °C 850 °C 1.10 1.30 1.50 Energy (eV)

SK-QD in MC (il PhC è costruito dopo)



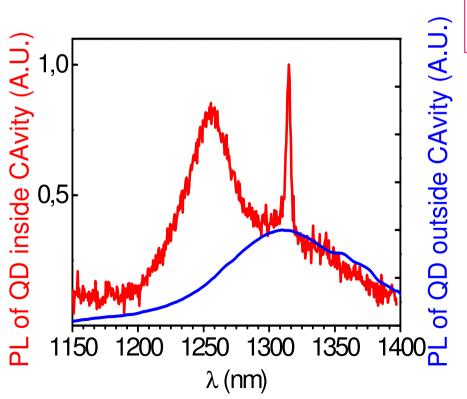
Colloidal QD in MC (il PhC è costruito prima)

RAPID COMMUNICATIONS

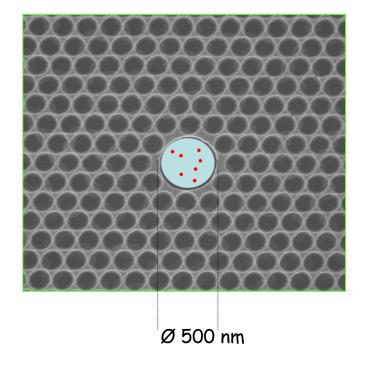
PHYSICAL REVIEW E 78, 045603(R) (2008)

Local nanofluidic light sources in silicon photonic crystal microcavities

Silvia Vignolini,^{1,*} Francesco Riboli,¹ Francesca Intonti,^{2,1} Michele Belotti,^{3,4} Massimo Gurioli,¹ Yong Chen,^{4,5} Marcello Colocci,¹ Lucio Claudio Andreani,³ and Diederik S. Wiersma¹



Local Source: colloidal PbS QDs suspended in Toluene



L. Cavigli^{1,*}, L. Lunghi², M. Abbarchi¹, A. Vinattieri¹ B. Alloing³, C. Zinoni³ A. Fiore³, A. Gerardino² P. Frigeri⁴ L. Seravalli⁴, S. Franchi⁴, and M. Gurioli¹

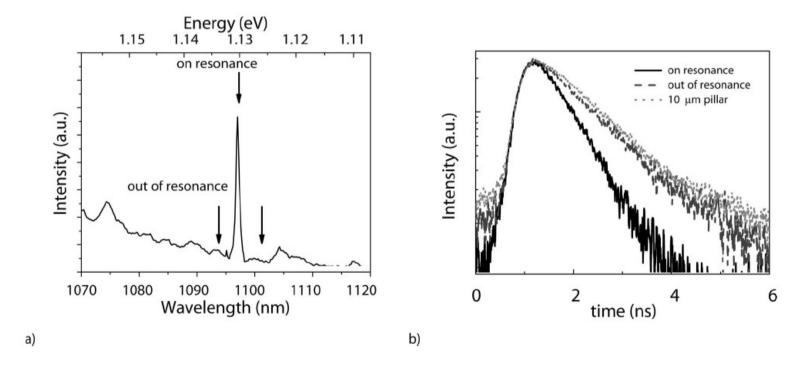
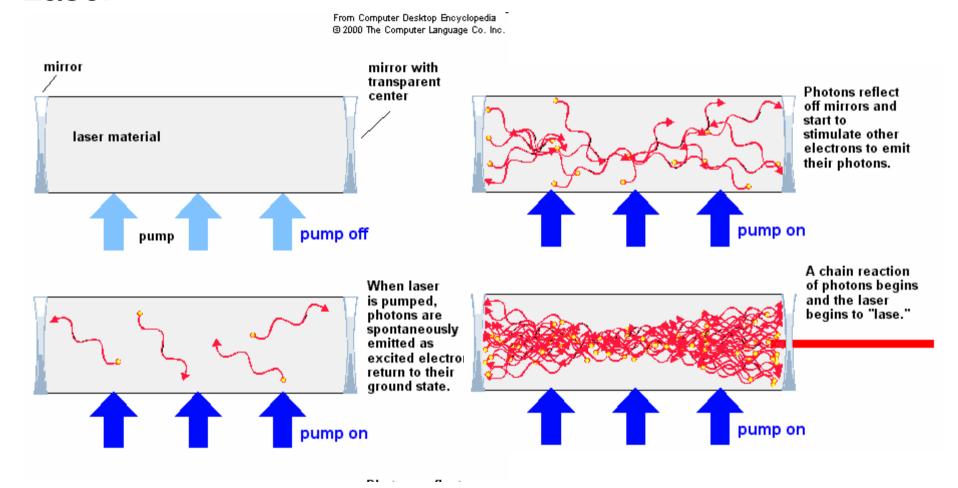


Figure 2 a) μ -PL emission spectra from single pillar with diameter $d=2 \mu m$ at 15 K; b) TR μ -PL emission spectra from single pillar with diameter $d = 2 \,\mu\text{m}$ at 15 K (taken at two wavelengths: 1097 nm on resonance, solid line, 1099 nm out of resonance, dashed line) compared with TR μ -PL emission spectra from single pillar with diameter $d=10~\mu m$ at 15 K, wavelength 1097 nm (dotted line).

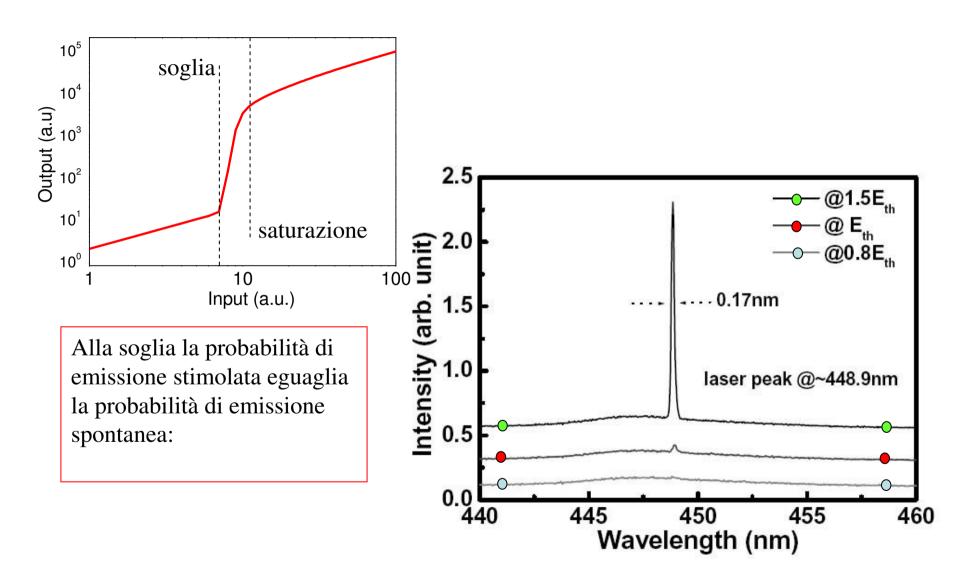
Applicazioni QDs in MC: Optoelettronica Laser senza soglia

Laser



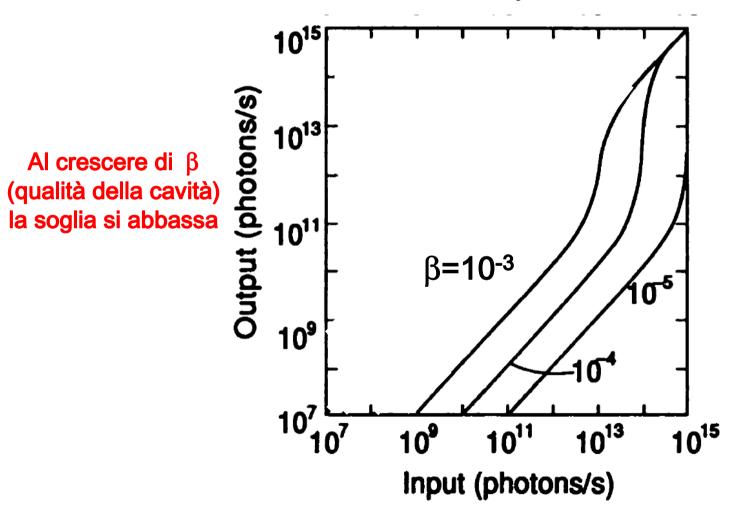
Sotto soglia domina emissione spontanea (perdite) Sopra soglia domina emissione stimolata

Soglia dei laser



Soglia dei laser

 $\beta = \frac{Numero di fotoni emessi nel modo laser}{Numero di fotoni emessi}$



In microcavità l'emissione spontanea avviene nel modo di cavità (modo laser) che è l'unico presente

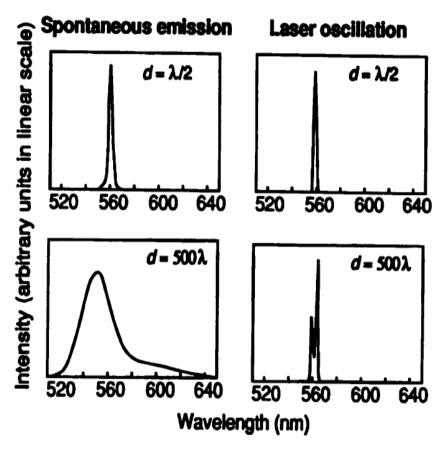
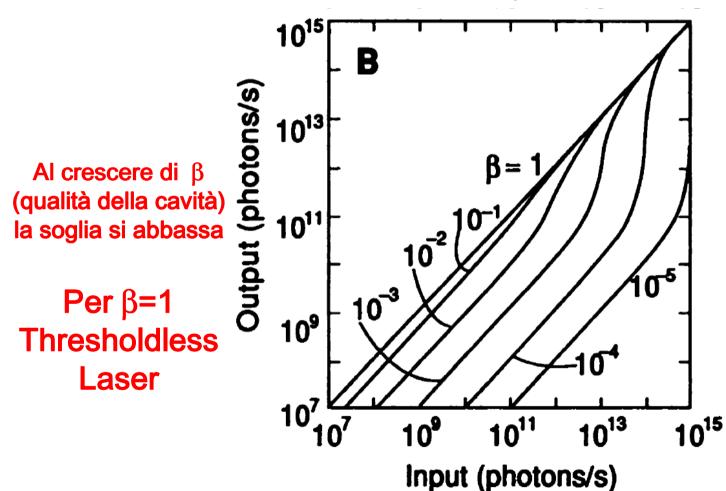


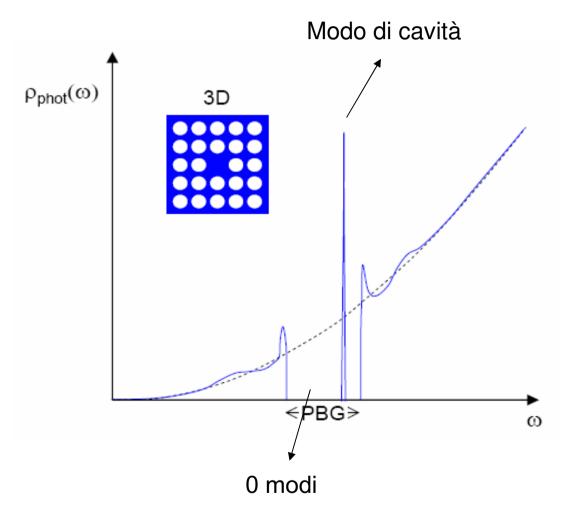
Fig. 8. Spontaneous and stimulated emission spectra of the $\lambda/2$ microcavity and the 500 λ cavity.

Soglia dei laser

 $\beta = \frac{Numero\ di\ fotoni\ emessi\ nel\ modo\ laser}{Numero\ di\ fotoni\ emessi}$

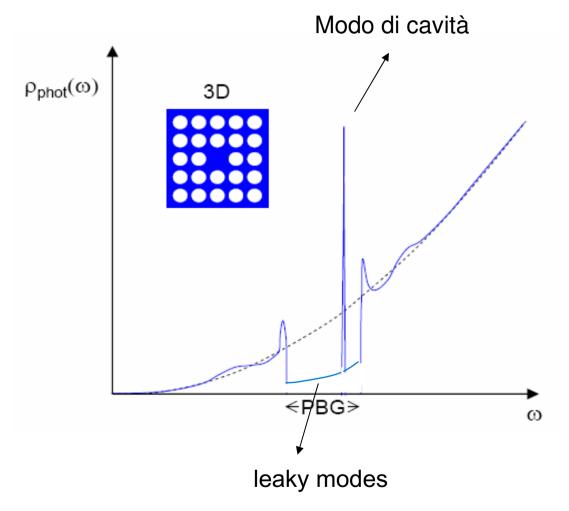


Cavità ideale



Emissione spontanea può avvenire solo nel modo di cavità ($\beta=1$)

Cavità reale



Emissione spontanea può avvenire anche nei leaky modes, $(\beta<1)$

Thresholdless Laser

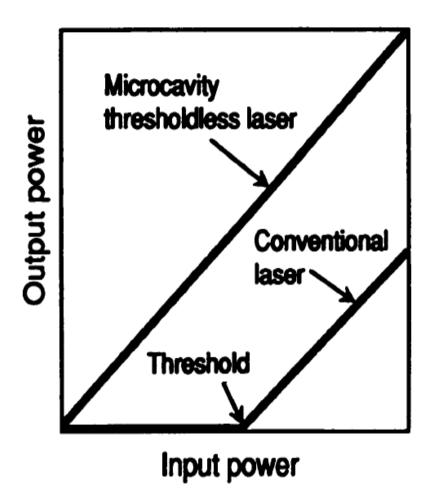
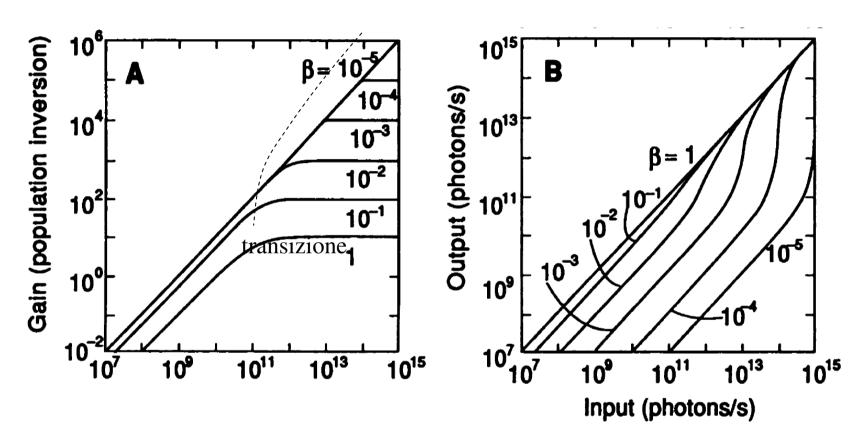


Fig. 4. Schematic of input-output characteristics of a conventional laser and a microcavity thresholdless laser.

Thresholdless Laser ma transizione da emissione spontanea a emissione stimolata



Calculated gain (A) and light output (B) versus input power for microcavities on logarithmic scales. β is the fraction of spontaneous emission coupled into the cavity mode.